



6.4W Psat, 41 dB Gain, 0.7 GHz to 3 GHz, AC Powered
Broadband GaAs GaN LDMOS High Power Amplifier
with Heatsink, Bench-Top, 110/240VAC, SMA

TECHNICAL DATA SHEET

PE15A5094

The PE15A5094 is an AC powered Bench-Top Power Amplifier that operates across a broadband frequency range from 700 MHz to 3 GHz. This 50 Ohm linear design utilizes GaAs and GaN semiconductor technology for high efficiency and exhibits impressive typical performance that includes 41 dB gain, +36 dBm P1dB, and +38 dBm Psat. Maximum RF input power (CW) is +2 dBm. The rugged MIL Grade aluminium package is finished in gray paint with SMA Female connectors at the RF input and output ports on the front panel. The rear panel supports an IEC 320-C14 AC power socket (IEC 320-C13 plug required), a fuse compartment, an On/Off switch, a dedicated package common ground connector, and an indicator light. The module supports a wide operating AC voltage range from 110VAC to 240VAC with 80 mA supply current. Designed for high reliability, the package supports an integrated heatsink and cooling fan and is suitable for outdoor operation (moisture exposure dependent on temperature and humidity conditions). The amplifier has an operational temperature range from -40°C to +85°C and meets a series of environmental test conditions including Altitude, Vibration, Humidity, and Shock.

Features

- AC Powered Bench-Top Power Amplifier
- 700 MHz to 3000 MHz
- Highly Linear GaAs and GaN Semiconductor Design
- Output Psat +38 dBm typ
- Output P1dB +36 dBm typ
- Small Signal Gain 41 dB typ
- Input VSWR 1.5:1 typ
- AC Supply 110-240VAC @ 80 mA
- Max RF Input Power (CW) +2 dBm
- 50 Ohm Design
- Integrated Heatsink and Cooling Fan
- RF Input and Output SMA Female Connectors
- On/Off Switch with Indicator Light
- Operational Temperature Range -40°C to +85°C
- Rugged MIL Grade Aluminum Package Design with Gray Paint finish
- Guaranteed Environmental Test Conditions Altitude, Vibration, Humidity, Shock

Applications

- Test & Measurement
- 5G Communication
- Wireless Infrastructure
- Military & Commercial Communications
- Military Electronic Systems
- Research & Development
- Microwave Radio
- VSAT
- Fiber Optics

Electrical Specifications (TA = +25°C, AC Current = 80 mA)

Description	Minimum	Typical	Maximum	Units
Frequency Range	0.7		3	GHz
Small Signal Gain	39	41	45	dB
Gain Flatness		±1.25		dB
Gain Variation Over Temp.		±1.5		dB
Input Power (CW)			+2	dBm
Pout at Sat.		+38		dBm
Output Power at 1 dB Compression Point	+34	+36		dBm
IMD3		25		dBc
Reverse Isolation		60		dB
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input Return Loss		1.5	2	dB
Supply Current (AC 110-220V)		80		mA

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Operating Temperature Range -40 +85 °C

Performance by Frequency

Biassing Up Procedure

Step 1 Connect input and output with 50 Ohm source and load with in band return loss better than 10dB.

Step 2 Connect AC Plug

Step 3 Flip switch to "ON" position

Power OFF Procedure

Step 1 Flip switch to "OFF" position

Step 2 Remove AC Plug

Step 3 Remove RF Connection

Absolute Maximum Rating

Parameter	Rating
Supply Voltage	110 to 240V AC
RF Input Power (RFIN)*	+2dBm

*Note: Maximum RF input power is defined to protect the amplifier from damage. Input power may be increased at the users own risk to achieve the full output power of the amplifier. Please reference gain and power curves and monitor the temperature

Mechanical Specifications

Size	
Length	10.63 in [270 mm]
Width	7.28 in [184.91 mm]
Height	3.78 in [96.01 mm]
Weight	7.94 lbs [3.6 kg]
Input Connector	SMA Female
Output Connector	SMA Female

Environmental Specifications

Temperature	
Operating Range	-40 to +85 deg C
Storage Range	-50 to +105 deg C
Humidity	100% RH at 35°C, 95% RH at 40°C

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Shock
Vibration
Altitude

20G for 11 msec half sinewave, 3 axis both directions
25g RMA (15 degrees 2KHz) endurance, 1 hour per axis
30,000 ft

Compliance Certifications (see [product page](#) for current document)

Plotted and Other Data

Notes:

- Values at +25 °C, sea level

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Amplifier Power-up Precautions

- 1.) Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module.
- 2.) Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling fan may also be used. Damage caused from overheating will void the warranty.
- 3.) Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate properly.
- 4.) Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- 5.) Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- 6.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues.
- 7.) Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- 8.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match.
- 9.) Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the Amplifier datasheet).
 P_{in} for Small Signal Gain = P1dB-SSG-10 dB
 P_{in} for P1dB = P1dB-SSG+1 dB
- 10.) Confirm the Network Analyzer is always connected to the Amplifier first before DC power is applied to the Amplifier.
- 11.) As long as the input and output ports of the amplifier are connected to a 50Ohm load and RF signal power is applied, the Amplifier can be powered up with DC voltage.
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the Amplifier and void the warranty.
- 13.) **Power Amplifier connected to an Antenna for signal transmission** - It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch will likely damage the Amplifier and void the warranty.
- 14.) The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational frequency band of the amplifier.

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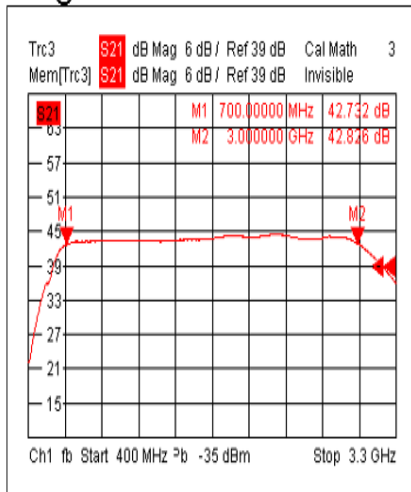
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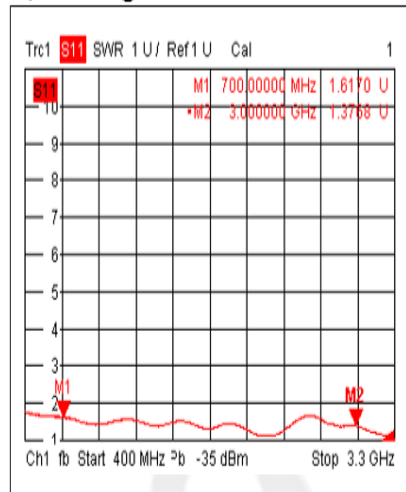
PE15A5094

Typical Performance Data

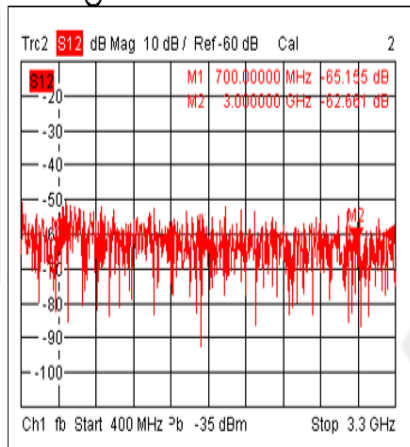
Gain@+25°C



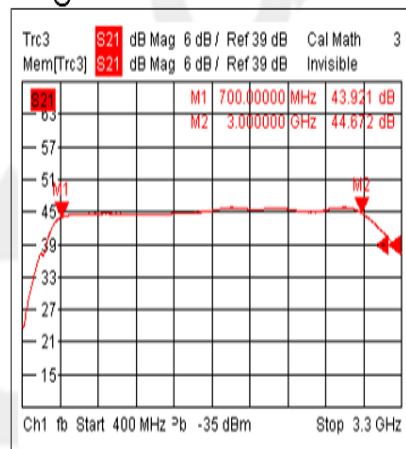
Input VSWR@+25°C



Isolation@+25°C



Gain@-40°C



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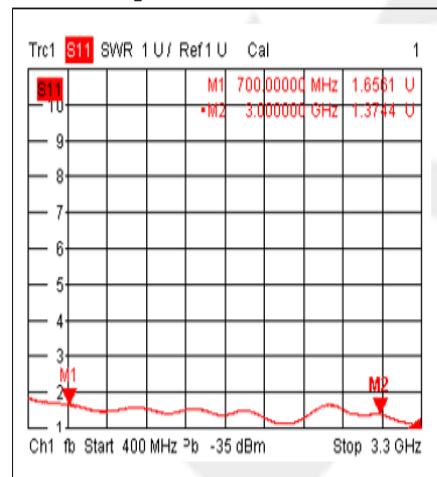


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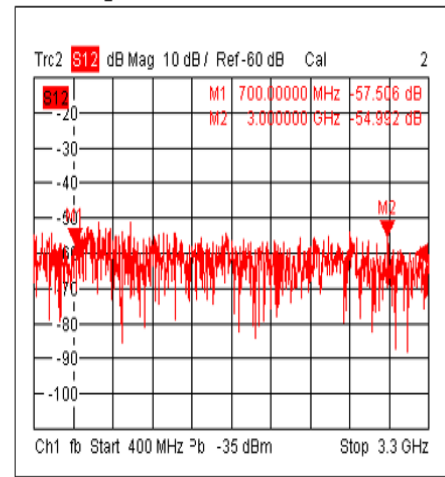
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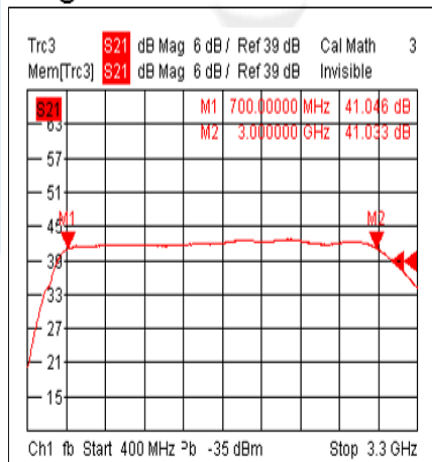
Input VSWR@-40°C



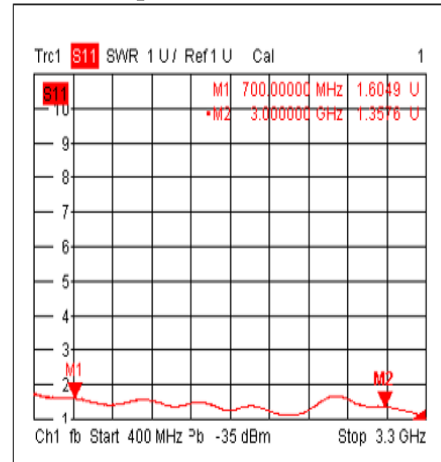
Isolation@-40°C



Gain@+70°C



Input VSWR@+70°C



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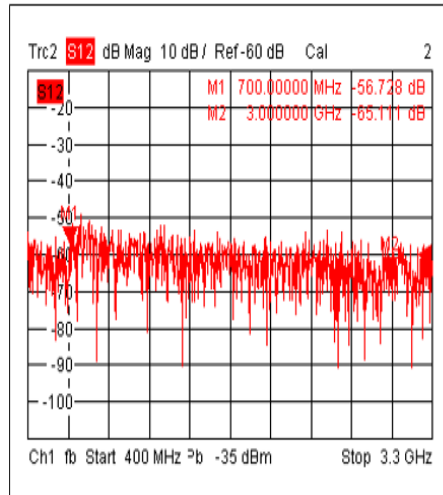


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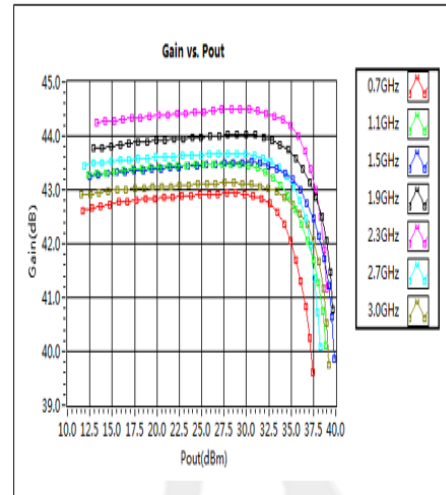
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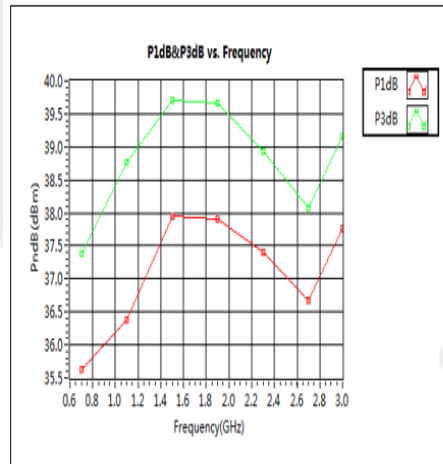
Isolation@+70°C



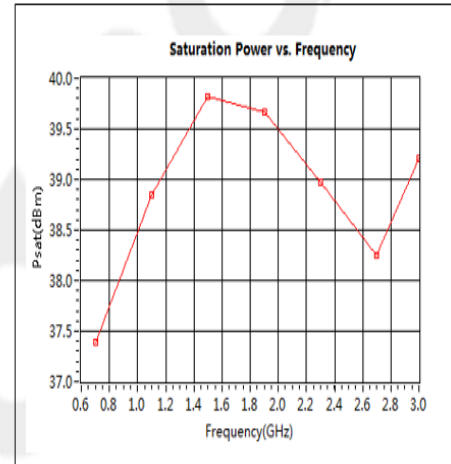
Gain vs. Output Power



P1dB & P3dB vs. Frequency



Saturated Power vs. Frequency



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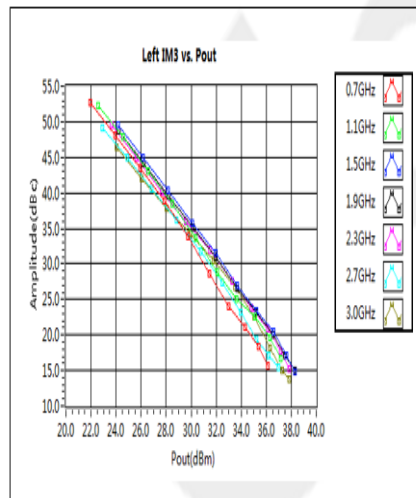


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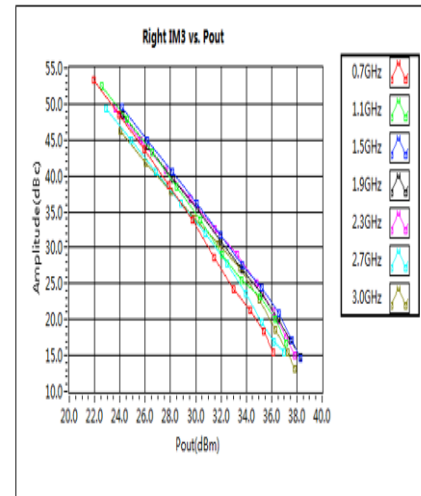
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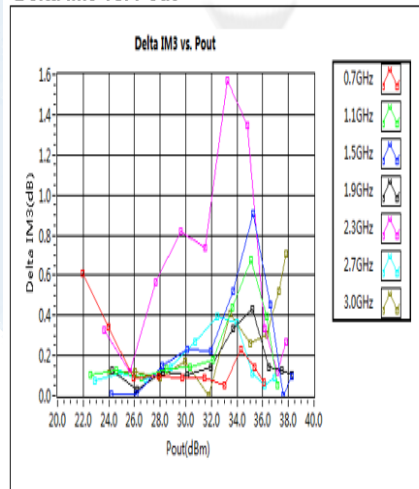
Left IM3 vs. Pout



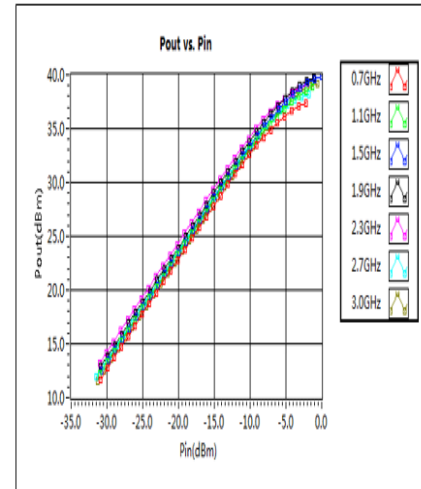
Right IM3 vs. Pout



Delta IM3 vs. Pout



Pout vs. Pin



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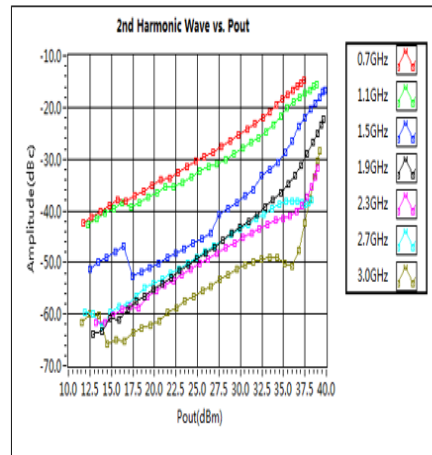


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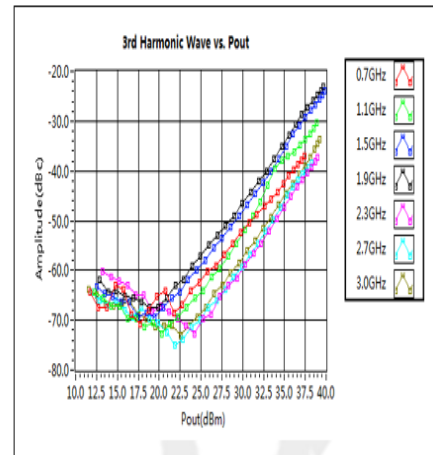
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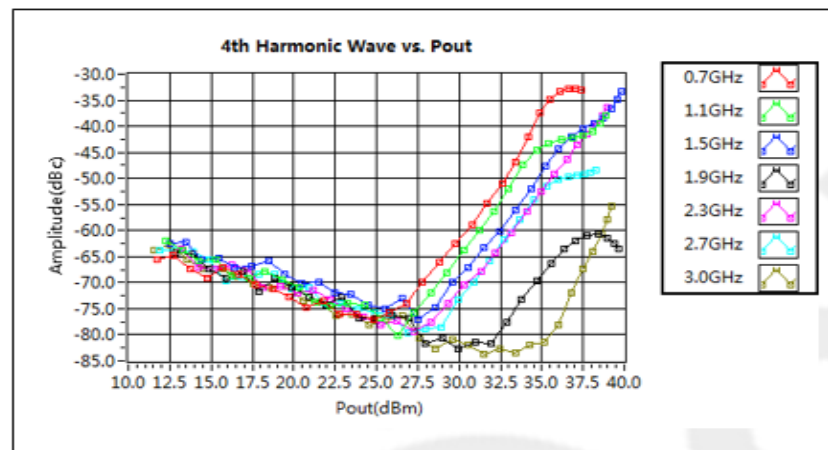
2nd Harmonic Wave Output Power



3rd Harmonic Wave Output Power



4th Harmonic Wave Output Power



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PE15A5094 CAD Drawing

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